










	<h2 style="color: red;">FQB22P10TM_F085</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQB22P10TM_F085</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> FQB22P10TM_F085 Fairchild/ON Semiconductor</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FQB22P10TM_F085.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 18500 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQB22P10TM_F085</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	FQB22P10TM_F085 Fairchild/ON Semiconductor
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	18500 pcs Stock
Serie	Automotive, AEC-Q101, QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 125W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	22A (Tc)
Rds On (Max) @ Id, Vgs	125 mOhm @ 11A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	50nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)




























FQB22P10TM\_F085 ist neu im Original, Suche FQB22P10TM\_F085 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB22P10TM\_F085 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB22P10TM\_F085: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 Not Actual Photo YIC International Co., Limited.	 <b>FQB22P10TM</b> Fairchild/ON Semiconductor MOSFET P-CH 100V 22A D2PAK	 <b>FQB24N08TM</b> Fairchild/ON Semiconductor MOSFET N-CH 80V 24A D2PAK	 Not Actual Photo YIC International Co., Limited.
 <b>FQB22P10</b> FAIRCHILD FQB22P10 FAIRCHILD	 <b>FQB20N60TM</b> FAIRCHILD FQB20N60TM FAIRCHILD	 <b>FQB22P10TM</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 22A D2PAK	 Not Actual Photo YIC International Co., Limited.
 <b>FQB22P10TM-F085</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 22A D2PAK	 <b>FQB25N33TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 330V 25A D2PAK	 <b>FQB25N33</b> FAIRCHI FQB25N33 FAIRCHI	

### heiße Teile

Mehr

 FQB17P10	 FQB17P10TM	 FQB17P10TM	 FQB19N10L	 FQB19N10LTM
 FQB19N10LTM	 FQB19N10TM	 FQB19N10TM	 FQB19N20	 FQB19N20C
 FQB19N20CTM	 FQB19N20CTM	 FQB19N20L	 FQB19N20LTM	 FQB19N20LTM
 FQB19N20TM	 FQB19N20TM	 FQB1N60TM	 FQB1N60TM	 FQB20N06L
 FQB20N60FTM	 FQB20N60TM	 FQB22P10	 FQB22P10TM	 FQB22P10TM
 FQB24N08TM	 FQB24N08TM	 FQB25N33	 FQB25N33TM	 FQB25N33TM
 FQB25N33TM_F085	 FQB27N25TM	 FQB27P06	 FQB27P06TM	 FQB27P06TM
 FQB2N50C	 FQB2N60TM	 FQB2N60TM	 FQB2N80TM	 FQB2N80TM
 FQB2NA90TM	 FQB2NA90TM	 FQB2P25TM	 FQB2P25TM	 FQB30N06
 FQB30N06L	 FQB30N06LTM	 FQB30N06LTM	 FQB30N06TM	 FQB30N06TM

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